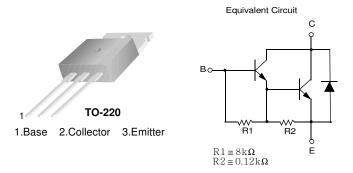


July 2009

TIP140T / TIP141T / TIP142T NPN Epitaxial Silicon Darlington Transistor

Features

- · Monolithic Construction With Built In Base-Emitter Shunt Resistors
- High DC Current Gain : h_{FE} = 1000 @ V_{CE} = 4V, I_{C} = 5A (Min.)
- Industrial Use
- Complement to TIP145T/146T/147T



Absolute Maximum Ratings * $T_A = 25 \,^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CBO}	Collector-Base Voltage : TIP140T : TIP141T : TIP142T	60 80 100	V V V	
V _{CEO}	Collector-Emitter Voltage : TIP140T : TIP141T : TIP142T	60 V 80 V 100 V		
V _{EBO}	Emitter-Base Voltage	5	V	
I _C	Collector Current (DC)	10	Α	
I _{CP}	Collector Current (Pulse)	15	Α	
I _B	Base Current (DC)	0.5	Α	
P _C	Collector Dissipation (T _C =25°C)	80	W	
TJ	Junction Temperature	150	°C	
T _{STG}	Storage Temperature	-65 to +150 °C		

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Electrical Characteristics $T_A = 25 \, ^{\circ}\! \text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V _{CEO} (sus)	Collector-Emitter Sustaining Voltage : TIP140T : TIP141T : TIP142T	I _C = 30mA, I _B = 0	60 80 100			V V V
I _{CEO}	Collector Cut-off Current : TIP140T : TIP141T : TIP142T	$V_{CE} = 30V, I_{B} = 0$ $V_{CE} = 40V, I_{B} = 0$ $V_{CE} = 50V, I_{B} = 0$			2 2 2	mA mA mA
I _{CBO}	Collector Cut-off Current : TIP140T : TIP141T : TIP142T	$V_{CB} = 60V, I_{E} = 0$ $V_{CB} = 80V, I_{E} = 0$ $V_{CB} = 100V, I_{E} = 0$			1 1 1	mA mA mA
I _{EBO}	Emitter Cut-off Current	$V_{BE} = 5V, I_{C} = 0$			2	mA
h _{FE}	DC Current Gain	$V_{CE} = 4V, I_{C} = 5A$ $V_{CE} = 4V, I_{C} = 10A$	1000 500			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 5A, I _B = 10mA I _C = 10A, I _B = 40mA			2 3	V V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C = 10A, I _B = 40mA			3.5	٧
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 4V, I_{C} = 10A$			3	٧
t _D	Delay Time	$V_{CC} = 30V, I_{C} = 5A$		0.15		μs
t _R	Rise Time	I _{B1} = 20mA I _{B2} = -20mA		0.55		μs
t _{STG}	Storage Time	$R_L = 6\Omega$		2.5		μs
t _F	Fall Time			2.5		μs

Typical Performance Characteristics

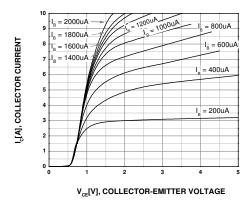


Figure 1. Static Characteristic

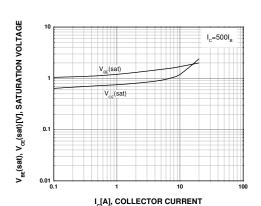


Figure 3. Collector-Emitter Saturation Voltage Base-Emitter Saturation Voltage

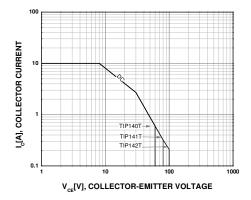


Figure 5. Safe Operating Area

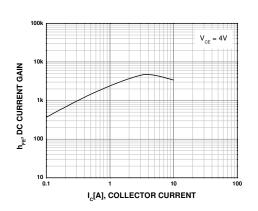


Figure 2. DC current Gain

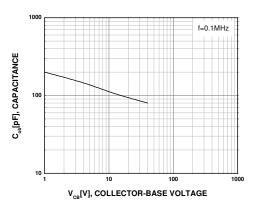


Figure 4. Collector Output Capacitance

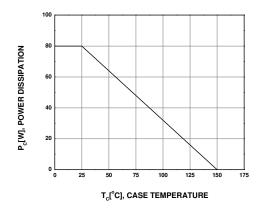
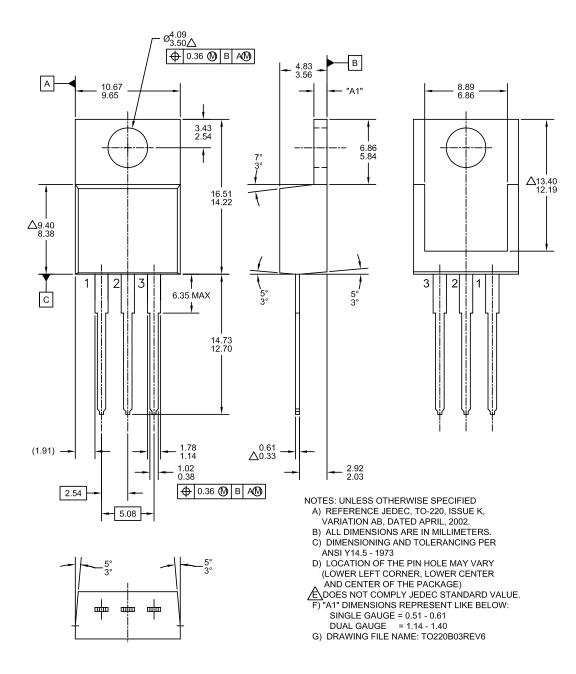


Figure 6. Power Derating

Physical Dimensions

TO-220







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Definition of Terms					
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